

**IN THE CLAIMS**

Please amend the claims as shown below. A complete listing of the claims is presented.  
cancel claims 4, 12 and 14 without prejudice or disclaimer of their underlying subject matter.

1. (canceled).

2. (Previously Amended) A semiconductor package comprising:

a first insulating substrate carrying a mounting portion for mounting a semiconductor device and a first electrically conductive pattern electrically connected to said semiconductor device;

a sidewall section formed upright around said mounting portion of said first insulating substrate;

a cavity defined by said first insulating substrate and the sidewall section and encapsulated by encapsulating resin as said semiconductor device is mounted on said mounting portion; and

a second insulating substrate provided in said cavity and on said sidewall section and carrying a second electrically conductive pattern electrically connected to said first electrically conductive pattern via through-holes formed in said sidewall section;

wherein solder lands are provided at least in said cavity on one surface of said first insulating substrate,

wherein a heat radiating plate is provided on an opposite surface of said first insulating substrate.

3. Cancelled

4. Cancelled

5. Cancelled

6. Cancelled

7. (Previously Amended) A method for the preparation of a semiconductor package comprising the steps of:

forming a mounting portion for mounting a semiconductor device and a first electrically conductive pattern for electrically connecting the semiconductor device on a first insulating substrate;

layering a spacer having an opening of substantially the same size as said mounting portion in one surface of said first insulating substrate;

mounting a semiconductor device in said mounting portion defined by said first insulating substrate and the opening provided in said spacer;

encapsulating said cavity with encapsulating resin after mounting said semiconductor device in said mounting portion;

layering a second insulating substrate carrying the a second electrically conductive pattern on one surface thereof on said spacer;

forming a through-hole for establishing electrical connection between said first electrically conductive pattern and said second electrically conductive pattern; and forming solder lands at least on said cavity on said electrically conductive pattern, wherein said second insulating substrate is a laminated sheet lined on one side with copper.

8. (Previously Amended) A method for the preparation of a semiconductor package comprising the steps of:

forming a mounting portion for mounting a semiconductor device and a first electrically conductive pattern for electrically connecting the semiconductor device on a first insulating substrate;

layering a spacer having an opening of substantially the same size as said mounting portion in one surface of said first insulating substrate;

mounting a semiconductor device in said mounting portion defined by said first insulating substrate and the opening provided in said spacer;

encapsulating said cavity with encapsulating resin after mounting said semiconductor device in said mounting portion;

layering a second insulating substrate carrying the a second electrically conductive pattern on one surface thereof on said spacer;

forming a through-hole for establishing electrical connection between said first electrically conductive pattern and said second electrically conductive pattern;

forming solder lands at least on said cavity on said electrically conductive pattern; and  
providing a heat radiating plate on the opposite surface of said first insulating substrate  
after forming said second electrically conductive pattern.

9. ~~(amended)~~ The semiconductor package according to claim 2, wherein said first  
insulating substrate is a laminated sheet lined ~~on both sides of the insulating substrate with~~  
~~copper on said one surface and on said opposite surface.~~

10. (Previously added) The semiconductor package according to claim 2, wherein said  
encapsulating resin is planarized.

11. (Previously added) The semiconductor package according to claim 2, wherein said  
second insulating substrate includes a cavity surface and a connection surface,

said cavity surface being adjacent and in contact with said cavity and said sidewall  
section, said connection surface being opposite said cavity surface,

said connection surface having a plurality of external electrical connections thereon, an  
external electrical connection of said plurality of external electrical connections providing a  
connection to an apparatus external from said semiconductor package,

some external electrical connections of said plurality of external electrical connections  
being opposite said cavity, and other external electrical connections of said plurality of external  
electrical connections being opposite said sidewall section.

12. Cancelled

13. (amended) A semiconductor package comprising:

a first insulating substrate carrying a mounting portion for mounting a semiconductor device and a first electrically conductive pattern electrically connected to said semiconductor device;

a sidewall section formed upright around said mounting portion of said first insulating substrate;

a cavity defined by said first insulating substrate and the sidewall section and encapsulated by encapsulating resin as said semiconductor device is mounted on said mounting portion; and

a second insulating substrate provided in said cavity and on said sidewall section and carrying a second electrically conductive pattern electrically connected to said first electrically conductive pattern via through-holes formed in said sidewall section;

wherein solder lands are provided at least in said cavity on one surface of said first insulating substrate,

wherein said second insulating substrate is a laminated sheet lined on one side with copperThe semiconductor package according to claim 4,

wherein said encapsulating resin is planarized.

14. Cancelled

15. (Previously added) The method according to claim 7, wherein said first insulating substrate is a laminated sheet lined on both sides of the insulating substrate with copper.

16. (Previously added) The method according to claim 7, wherein said encapsulating resin is planarized prior to said step of layering said second insulating substrate.

17. (Previously added) The method according to claim 7, wherein said second insulating substrate includes a cavity surface and a connection surface,

said cavity surface being adjacent and in contact with said cavity and said sidewall section, said connection surface being opposite said cavity surface,

said connection surface having a plurality of external electrical connections thereon, an external electrical connection of said plurality of external electrical connections providing a connection to an apparatus external from said semiconductor package,

some external electrical connections of said plurality of external electrical connections being opposite said cavity, and other external electrical connections of said plurality of external electrical connections being opposite said sidewall section.

18. (Previously added) The method according to claim 8, wherein said first insulating substrate is a laminated sheet lined on both sides of the insulating substrate with copper.

19. (Previously added) The method according to claim 8, wherein said encapsulating resin is planarized prior to said step of layering said second insulating substrate.

20. (Previously added) The method according to claim 8, wherein said second insulating substrate includes a cavity surface and a connection surface,  
said cavity surface being adjacent and in contact with said cavity and said sidewall section, said connection surface being opposite said cavity surface,  
said connection surface having a plurality of external electrical connections thereon, an external electrical connection of said plurality of external electrical connections providing a connection to an apparatus external from said semiconductor package,  
some external electrical connections of said plurality of external electrical connections being opposite said cavity, and other external electrical connections of said plurality of external electrical connections being opposite said sidewall section.